# Supertex inc.



### **Features**

- ► Free from secondary breakdown
- Low power drive requirement
- Ease of paralleling
- Low C<sub>iss</sub> and fast switching speeds
- Excellent thermal stability
- Integral SOURCE-DRAIN diode
- High input impedance and high gain
- Complementary N- and P-Channel devices

## **Applications**

- Motor controls
- Converters
- Amplifiers
- Switches
- Power supply circuits
- Drivers (relays, hammers, solenoids, lamps, memories, displays, bipolar transistors, etc.)

### **General Description**

The Supertex 2N7008 is an enhancement-mode (normally-off) transistor that utilizes a vertical DMOS structure and Supertex's well-proven silicon-gate manufacturing process. This combination produces a device with the power handling capabilities of bipolar transistors, and the high input impedance and positive temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, this device is free from thermal runaway and thermally-induced secondary breakdown.

Supertex's vertical DMOS FETs are ideally suited to a wide range of switching and amplifying applications where very low threshold voltage, high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

## **Ordering Information**

Device	Package	BV <sub>DSS</sub> /BV <sub>DGS</sub> (V)	R <sub>DS(ON)</sub> (max) (Ω)	l <sub>¤(ON)</sub> (min) (mA)	
2N7008	TO 02	60	7.5	500	
2N7008-G	TO-92	60	7.5		





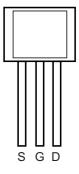
## **Absolute Maximum Ratings**

Parameter	Value			
DRAIN to SOURCE voltage	BV <sub>DSS</sub>			
DRAIN to GATE voltage	BV <sub>DGS</sub>			
GATE to SOURCE voltage	±30V			
Operating and storage temperature	-55°C to +150°C			
Soldering temperature <sup>1</sup>	+300°C			

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

Note 1. Distance of 1.6mm from case for 10 seconds.

## **Pin Configuration**



TO-92 (front view)

<sup>-</sup>G indicates package is RoHS compliant ('Green')

# Electrical Characteristics (T<sub>A</sub> = 25°C unless otherwise specified)

Symbol	Parameter	Min	Тур	Max	Units	Conditions	
BV <sub>DSS</sub>	DRAIN-to-SOURCE breakdown voltage	60	-	-	V	$V_{GS} = 0V, I_{D} = -10\mu A$	
$V_{\rm GS(th)}$	GATE threshold voltage	1.0	-	2.5	V	$V_{GS} = V_{DS}$ , $I_{D} = 250 \mu A$	
I <sub>GSS</sub>			-	100	nA	$V_{GS} = \pm 30 \text{V}, V_{DS} = 0 \text{V}$	
		-	-	1.0	μA	$V_{GS} = 0V, V_{DS} = 50V$	
I <sub>DSS</sub>	Zero GATE voltage drain current	-	-	500	μA	$V_{GS} = 0V, V_{DS} = 50V,$ $T_A = 125^{\circ}C$	
I <sub>D(ON)</sub>	ON-state DRAIN current	500	-	-	mA	$V_{GS} = 10V, V_{DS} \ge 2.0V_{DS(ON)}$	
В	Static DRAIN-to-SOURCE ON-state resistance	-	-	7.5	Ω	$V_{GS} = 5.0V, I_{D} = 50mA$	
R <sub>DS(ON)</sub>		-	-	7.5		V <sub>GS</sub> = 10V, I <sub>D</sub> = 500mA	
G <sub>FS</sub>	Forward transconductance	80	-	-	mmho	$V_{DS} = 10V, I_{D} = 0.2A$	
C <sub>ISS</sub>	Input capacitance	-	-	50			
C <sub>oss</sub>	Common SOURCE output		-	25	pF	$V_{GS} = 0V, V_{DS} = 25V,$ f = 1.0MHz	
C <sub>RSS</sub>	Reverse transfer capacitance	-	-	5			
t <sub>(ON)</sub>	Turn-ON time	-	-	20	no	$V_{DD} = 30V$ , $I_{D} = 200$ mA, $R_{GEN} = 25\Omega$	
t <sub>(OFF)</sub>	Turn-OFF time	-	-	20	ns		
V <sub>SD</sub>	Diode forward voltage drop		-	1.5	V	V <sub>GS</sub> = 0V, I <sub>SD</sub> = 150mA	

#### Notes

1.All D.C. parameters 100% tested at 25°C unless otherwise stated. (Pulse test: 300µs pulse, 2% duty cycle.)

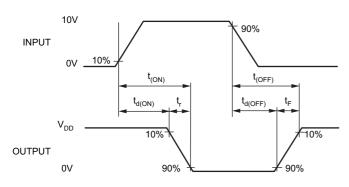
2.All A.C. parameters sample tested.

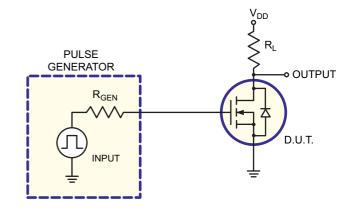
### **Thermal Characteristics**

Device	Package	I <sub>D</sub> (continuous) <sup>⁺</sup> (mA)	I <sub>D</sub> (pulsed) (A)	Power Dissipation @T <sub>c</sub> = 25°C (W)	θ <sub>ja</sub> (°C/W)	θ <sub>j</sub> (°C/W)	I <sub>DR</sub> * (mA)	I <sub>DRM</sub> (A)
2N7008	TO-92	230	1.3	1.0	170	125	230	1.3

### Notes:

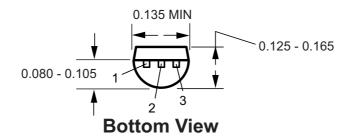
# **Switching Waveforms and Test Circuit**

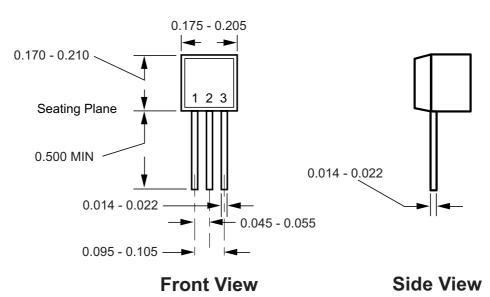




<sup>\*</sup>  $I_D$  (continuous) is limited by max rated  $T_T$ 

## **TO-92 Package Outline**





### Notes:

All dimensions are in millimeters; all angles in degrees.

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <a href="http://www.supertex.com/packaging.html">http://www.supertex.com/packaging.html</a>.)

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